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β-particle energy-summing correction for β-delayed proton emission measurements

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Abstract

A common approach to studying β-delayed proton emission is to measure the energy of the emitted proton and corresponding nuclear recoil in a double-sided silicon-strip detector (DSSD) after implanting the β-delayed proton-emitting (\(\beta p\)) nucleus. However, in order to extract the proton-decay energy from the total decay energy which is measured, the decay (proton + recoil) energy must be corrected for the additional energy implanted in the DSSD by the β-particle emitted from the \(\beta p\) nucleus, an effect referred to here as β-summing. We present an approach to determine an accurate correction for β-summing. Our method relies on the determination of the mean implantation depth of the \(\beta p\) nucleus within the DSSD by analyzing the shape of the total (proton + recoil + β) decay energy distribution shape. We validate this approach with other mean implantation depth measurement techniques that take advantage of energy deposition within DSSDs upstream and downstream of the implantation DSSD.

Keywords:
β-delayed proton emission; GEANT4; DSSD
PACS: 29.30.Ep, 29.40.Wk

1. Introduction

β-delayed proton emission experiments can be used to populate proton-emitting states in nuclei which are otherwise difficult to access. Such proton-emitting states can be of interest to nuclear astrophysics and nuclear structure studies [1–3]. Rare-isotope beam facilities that produce short-lived isotopes either by projectile fragmentation or using the isotope separation online (ISOL) technique provide the opportunity to study the exotic nuclei which exhibit β-delayed proton emission, \(\beta p\) nuclei.

To date, the most common method for studying \(\beta p\) nuclei employs the production of nuclei via projectile fragmentation followed by the subsequent implantation of the \(\beta p\) nucleus into a double-sided silicon-strip detector (DSSD) with a thickness on the order of 50-1000 \(\mu\)m [e.g.: 1, 2, 4–7]. After implantation into the DSSD, the \(\beta p\) nucleus undergoes β-delayed proton emission and the energy of the proton and the corresponding nuclear recoil (referred to here as the proton-decay energy) is then detected within the DSSD. The high degree of segmentation in the DSSD, in the case studied here forty 1 mm-pitch strips in both planar dimensions, enables the correlation of implants and decays, even with implantation rates on the order of 1 kHz. This capability has the advantage of turning the contaminant nuclei in the beam whose decays are well understood into calibration nuclei.

One consequence of using the projectile fragmentation production method is a relatively large energy spread of the ions of interest that impinge on the implantation DSSD. This large energy spread requires a relatively thick DSSD to stop all ions of interest in the active area of the detector. However, an undesired consequence of this approach is the additional energy deposited in the DSSD from the β-particle which is emitted almost simultaneously with the proton in β-delayed proton emission. Therefore what is measured is not the proton-decay energy, but rather the total decay energy. This is a process we refer to here as the β-summing effect. An example in the literature is shown in Figure 8 of [4], where it is evident that the Gaussian peak of proton energy deposition is shifted to higher energy and convolved with a high-energy tail due to the addition of β-particle energy deposition. The β-summing effect is one of the dominant uncertainties in determining the energy deposited by a proton decay within a DSSD after a β-delayed decay.

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proton emission event, contributing several tens of keV to energy resolutions of ~50–100 keV for proton-decay energies of a few MeV [1, 5]. As such, it is necessary to take into account \( \beta \)-summing for studies of \( \beta \)p nuclei whose results rely on a precise proton-decay energy determination, which is often the case for nuclear astrophysics [e.g. 1].

We present here an approach to addressing the problem of \( \beta \)-summing. This method, which was employed in the analysis of data presented in Reference [1], consists of determining the mean implantation depth of a \( \beta \)p nucleus within a DSSD by reproducing the measured shape of the total (proton + \( \beta \)) energy-deposition histogram for \( \beta \)-delayed proton-emission events with simulations. The following section, Section 2, will discuss the data collected and \texttt{GEANT4} simulations used to accomplish the \( \beta \)-summing correction analysis, as well as the simulation validation. Section 3 will present our newly developed mean implantation depth determination method, which is essential in determining the \( \beta \)-summing correction, and Section 4 will provide comparisons to alternative mean implantation depth determination methods. Section 5 will describe the process of obtaining the \( \beta \)-summing correction itself.

2. Measurements and Simulations

We focus on the \( \beta \)-summing correction which was developed using data from a \( \beta \)-delayed proton emission experimental campaign performed at the National Superconducting Cyclotron Laboratory (NSCL), partially described in Reference [1]. The data chosen are typical of that collected on \( \beta \)p nuclei produced via projectile fragmentation, with subsequent implantation into a relatively thick DSSD. Additionally, properties of the studied nuclei are well known from previously published data. As such, they provide an ideal case to study our proposed \( \beta \)-summing correction method. \texttt{GEANT4} [8] was chosen to simulate the measurements due to its flexibility and rigorously validated physics packages [See e.g. 9]. The following subsections provide detailed descriptions of the experimental data collection and the simulations thereof.

2.1. \( \beta \)-summing data collection

The data to assess \( \beta \)-summing were collected using \( \beta \)p emitting nuclei which were produced via projectile fragmentation using the Coupled Cyclotron Facility at the NSCL [10]. The primary beam used to produce the \( \beta \)p nuclei \( ^{24}\text{Si} \) and \( ^{26}\text{Mg} \) was \( ^{36}\text{Ar} \), whereas a \( ^{78}\text{Kr} \) primary beam was used to produce the \( \beta \)p nucleus \( ^{86}\text{Kr} \). The primary beams were impinged on a beryllium target of thickness 1060 mg/cm\(^2\) for \( ^{36}\text{Ar} \) and 141 mg/cm\(^2\) for \( ^{78}\text{Kr} \) at an energy of 150 MeV/u. The resultant cocktail beams were purified first with the A1900 fragment separator [11] and then further purified via the Radio Frequency Fragment Separator [12] prior to implantation within the central DSSD of the Beta Counting System (BCS) [13], where

\( \beta \)-delayed proton emission events were measured. The implantation rate within the BCS was ~100 Hz.

![Figure 1: Schematic arrangement of the silicon detectors within the NSCL BCS in the configuration used for the experimental campaign described in the text. Scint1 is a BC400 timing scintillator, Degrader is an aluminum foil, PIN are single-sided silicon strip detectors, and DSSD are double-sided silicon-strip detectors. The thickness of each detector is indicated below it in the figure and the role of each detector is indicated by the label within the detector. Relative longitudinal spacings of the detectors are listed in Table 1.](Image)

<table>
<thead>
<tr>
<th>Detector</th>
<th>Thickness [mm]</th>
<th>Relative position [mm]</th>
</tr>
</thead>
<tbody>
<tr>
<td>Scint1</td>
<td>140 ( \mu )m</td>
<td>0.00</td>
</tr>
<tr>
<td>Degrader</td>
<td>140 ( \mu )m</td>
<td>-140 ( \mu )m</td>
</tr>
<tr>
<td>PIN1</td>
<td>0.503</td>
<td>-7.73</td>
</tr>
<tr>
<td>PIN2</td>
<td>0.996</td>
<td>-5.87</td>
</tr>
<tr>
<td>PIN3</td>
<td>0.983</td>
<td>-3.68</td>
</tr>
<tr>
<td>DSSD1</td>
<td>0.525</td>
<td>-1.73</td>
</tr>
<tr>
<td>DSSD2</td>
<td>0.525</td>
<td>0.00</td>
</tr>
<tr>
<td>DSSD3</td>
<td>0.525</td>
<td>2.23</td>
</tr>
<tr>
<td>PIN4</td>
<td>0.998</td>
<td>4.19</td>
</tr>
</tbody>
</table>

Table 1: Thicknesses and relative longitudinal positions (along the beam axis) with respect to the implantation DSSD, DSSD2, of silicon detectors used in the \texttt{GEANT4} simulations and experimental setup of the \( \beta \)-delayed proton emission measurements described in this paper and sketched in Figure 1.

A schematic of the experiment set-up is given in Figure 1 and the relative longitudinal positions of detectors within the BCS are listed in Table 1. Particle identification of implanted nuclei was performed using the \( \Delta E - TOF \) technique, where timing signals were provided by the Coupled Cyclotron RF and a 140 \( \mu \)m-thick BC400 scintillator upstream of the BCS and three PIN detectors, of thickness 503 \( \mu \)m, 996 \( \mu \)m, and 983 \( \mu \)m, within the BCS upstream of the implantation detector were used to measure energy loss. An aluminum degrader upstream of the BCS was used to ensure implantation of nuclei of interest within the central DSSD of the BCS by adjusting the degrader’s angle with respect to the beam direction. A stack of three 525 \( \mu \)m DSSDs, model BB1 from Micron Semiconductor Ltd., located downstream of the first three PIN detectors in the BCS were used to detect implantations from beam fragments and \( \beta \)-particles from subsequent decays. The central DSSD was intended for implantation
of \(\beta\)p nuclei. A single 998 \(\mu\)m-thick PIN detector was located downstream of the DSSD stack within the BCS to provide a veto for light fragments accompanying the beam which could otherwise be mistaken for \(\beta\)-particles within the DSSD stack. The detectors within the BCS were surrounded by a 13 cm-diameter aluminum cylinder, which was itself surrounded by the Segmented Germanium Array (SeGA) in the beta-configuration [14] in order to measure proton emission branchings and decays to non-proton-emitting states with high resolution.

\(\beta\)-delayed proton emission events were correlated in time with \(\beta\)p nuclei previously implanted in the same DSSD pixel, while SeGA provided complementary \(\gamma\)-detection. A notable contaminant which accompanied the \(\beta\)p nucleus \(69\)Kr was \(67\)Se (See Figure 2 of Reference [1]), as this was used to determine the implantation DSSD detection threshold (See Section 2.3.). Before and after the projectile fragmentation experiments, the calibration \(\alpha\)-source \(228\)Th was employed to characterize the energy resolution of the DSSDs.

2.2. GEANT4 simulations

We employ the Monte Carlo particle transport software GEANT4 [8] version 4.9.6.02 to simulate the \(\beta\)-delayed proton emission measurements described in the previous subsection. Detector features such as geometry, orientation, and resolution were included in the GEANT4 simulations, though for the purpose of simplification the BCS was modeled as a stack of free-floating silicon detectors within an aluminum cylinder. This simplification is anticipated to have no effect on the final result. Each DSSD is segmented into \(40 \times 40\) strips with a 1 mm pitch, i.e. consisting of 1600 \(1 \times 1\) mm\(^2\) virtual pixels. Each PIN detector is \(5\times5\) cm\(^2\) and has no segmentation.

![Figure 2: (color online.) \(\beta\)-energy distributions for \(\beta^+\) (solid orange line) and \(\beta^-\) (dashed blue line) decays for a \(\beta\)-decay with \(Q = 8984\) keV.](image)

\(\beta\)-energy spectra were sampled from the \(\beta\)-decay distribution given by the Fermi theory of \(\beta\)-decay [15], defined by the \(Q\)-value between the initial and final states.

An example of \(\beta^+\) and \(\beta^-\) (for comparison) energy distributions are shown in Figure 2. Strictly speaking, the final shapes of the \(\beta\)-decay energy distribution depends on nuclear corrections related to the charge and size of the parent nucleus [16–20]. However, these higher-order nuclear corrections result in a relatively minor change (e.g. compared to small changes in the decay \(Q\)-value) in the overall decay spectrum shape [21, 22] and so these nuclear corrections can be safely neglected. Though the \(Q\)-value significantly affects the energy spectrum of emitted \(\beta\)-particles, we demonstrate (in Section 2.4) a relatively small sensitivity of our reported results to the choice of \(\beta\)-decay \(Q\)-value, which could vary due to mass uncertainties and/or different assumed final states of the decay.

2.3. Simulation validation

Since a proton from an implanted \(\beta\)p nucleus with an energy up to a few MeV has a mean free path up to tens of microns\(^1\), it generally implants 100\% of its energy within the DSSD, as does the corresponding nuclear recoil, and therefore the critical element of the GEANT4 simulations requiring validation is the partial energy deposition of the \(\beta\)-particle within the DSSD. The simulation of \(\beta\)-particle energy deposition within the DSSD was validated via comparison to experimental measurements of the well-studied \(\beta\)-emitter \(67\)Kr [23], which accompanied the production of \(69\)Kr as a contaminant from fragmentation of \(78\)Kr (Shown in Figure 2 of Reference [1]).

Comparison to data required a determination of the energy resolution and energy detection threshold of the implantation DSSD. The energy resolution, which was observed to be dominated by electronic noise and thus independent of energy, was determined by fitting several Gaussian distributions to the spectrum of a \(228\)Th \(\alpha\)-source. We used a probabilistic criterion to mimic the analog to digital converter detection threshold (which is not a fixed energy due to electronic variations that affect the conversion from deposited energy to a voltage), where we used the acceptance-rejection method [24] to sample from a probability distribution given by the following equation,

\[
\text{threshold}(E) = 0.5 \left( 1 + \tanh \left( \frac{E - c}{d} \right) \right),
\]

which is plotted in Figure 3.

The two free parameters of Equation 1 used to mimic the \(\beta\) detection threshold for a \(\beta\)-particle with energy \(E\), namely the diffuseness \(d\) and centroid \(c\) of the hyperbolic tangent, were determined via a \(\chi^2\)-minimization comparison between simulations and data for \(67\)Se \(\beta\)-decays to be 60 keV and 280 keV, respectively. Equation 1 was applied to a GEANT4 simulation of \(67\)Se \(\beta\)-decays distributed within a 0.525 mm-thick DSSD that mirrored the experimental conditions for the \(67\)Se \(\beta\)-decay measurement discussed in Section 2.1 (Also described in Reference [1]). The \(67\)Se

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\(^1\)http://physics.nist.gov/Star


\[ \beta \]-decay location within the DSSD was sampled from a fit to data for the planar location and sampled from a depth distribution calculated with LISE++ [25]. Following the acceptance-rejection method, the \( \beta \)-energy \( E \), which was sampled in a Monte Carlo fashion from the \( \beta \)-energy distribution for \( ^{67} \text{Se} \), was then used as input to Equation 1. The result of this calculation was compared to a randomly generated number using a box-like uniform distribution. This was used to decide whether a \( \beta \)-particle was ‘detected’ or discarded. The simulation results were in good agreement with the experimental data, as seen in Figure 4. We note that the fraction of rejected events with respect to recorded events for the \textit{GEANT4} simulation, 66%, was in agreement with the experimentally measured ratio of detected \( ^{67} \text{Se} \) implants to detected \( ^{67} \text{Se} \) \( \beta \)-decays, roughly 68%.

For the DSSD energy-calibration we used a \( ^{228} \text{Th} \) \( \alpha \)-source, providing energies \( E_\alpha = 5.400, 5.685, 6.288, \) and \( 6.778 \text{ MeV} \) [26], and known \( \beta \)-delayed protons from \( ^{20} \text{Mg} \), \( E_\beta = 0.806, 1.679, \) and \( 2.692 \text{ MeV} \) [6]\(^2\), and \( ^{23} \text{Si} \), \( E_\beta = 1.32, 2.40, 2.83, \) and \( 3.04 \text{ MeV} \) [7], which were \( ^{36} \text{Ar} \) fast-beam fragments measured within the implantation DSSD. Note that the use of measured energies from \( \beta \)-delayed protons from \( ^{20} \text{Mg} \) and \( ^{23} \text{Si} \) as calibration points required the \( \beta \)-summing correction (discussed in Section 5) to be applied. The uncertainty of the proton energies from \( \beta \)\( p \) emitters \( ^{20} \text{Mg} \) and \( ^{23} \text{Si} \), which ranged from 15-60 keV, included a systematic uncertainty associated with the \( \beta \)-summing correction present in published studies [6, 7] which determined the proton-decay energies. References [6] and [7] each corrected for \( \beta \)-summing, however they do not elaborate on precisely how this was done.

\(^2\)The first two proton-decay energies have been measured to higher-precision by [27]. The results are consistent with [6] (whose energies were used for this work and the corresponding work [1]) within uncertainties and therefore would not impact the reported results.

Figure 3: Likelihood of event detection as a function of energy deposited within the implantation DSSD, as given by Equation 1 with \( c=60 \text{ keV} \) and \( d=280 \text{ keV} \).

2.4. Sensitivity to decay \( Q \)-value

Though the reported \( \beta \)-summing correction technique relies on knowing the \( \beta \)-energy spectrum, we demonstrate that our results are relatively insensitive to uncertainties in the \( \beta \)-decay \( Q \)-value, where here the \( Q \)-value is to the final state and not necessarily the ground state.

The employed \( Q \)-values in this work were 9073 keV for \( ^{67} \text{Se} \) [28] (where a 100% branch to the ground state was assumed), 6686 keV for the \( ^{20} \text{Mg} \) decay branch to the proton emitting state of \( ^{20} \text{Na} \) at 806 keV [6, 28], 12083 keV for the \( ^{23} \text{Si} \) decay branch to the proton emitting state of \( ^{23} \text{Al} \) at 2400 keV [7, 28], 12655 keV for the \( ^{69} \text{Kr} \) decay to the \( ^{69} \text{Br} \) ground state [1, 28], and 9502 keV for the \( ^{69} \text{Kr} \) decay to the proton emitting state of \( ^{69} \text{Br} \) at 2940 keV [1, 28, 29]. Since the simulations were performed for the analysis presented in Reference [1], a more recent mass evaluation has been published [30]. In no case is the resultant updated \( Q \)-value different by the employed \( Q \)-value by more than 90 keV.

\textit{GEANT4} simulations were performed for the \( ^{67} \text{Se} \beta \)-decay modifying the \( Q \)-value from Reference [30] by several MeV, mimicking \( \beta \)-decay channels into excited states of the daughter, in order to compare the \( \beta \)-energy deposition within the implantation DSSD. Though the initial \( \beta \)-energy spectra varied dramatically, the spectra for \( \beta \)-energy deposition within the DSSD were remarkably similar for large modifications to the initial \( Q \)-value, as shown in Figure 5. In fact, the \( \beta \)-energy deposition spectra were nearly indistinguishable, except for the simulation which employed a \( Q \)-value reduced by 4 MeV from the nominal value of 9 MeV. This insensitivity to relatively substantial modifications of the decay \( Q \)-value is not surprising, but rather

Figure 4: (color online.) Comparison of energy deposited by \( ^{67} \text{Se} \beta^+ \)-decays implanted in a 0.525 mm-thick DSSD as simulated by \textit{GEANT4} (solid line) and measured (points), where a detection threshold given by Equation 1 with \( d = 60 \text{ keV} \) and \( c = 280 \text{ keV} \) has been applied to the \textit{GEANT4} spectrum. Note that the simulation and data have the same binning, where the area of the simulation has been scaled to match the data.
expected upon inspection of the analytic relation for energy deposition of $\beta$-particles in solid media. Figure 6 shows the relation taken from Reference [31] for $\beta$-energy deposition within 260 $\mu$m of silicon for $\beta$-particles ranging from 100-13000 keV. There it is apparent that $\beta$-particles over an energy span of $\sim$2000-13000 keV are expected to deposit nearly the same amount of energy when traveling through the same thickness of silicon. Therefore, sensitivity to the $Q$-value, due to the choice of decay final state or the state’s energy uncertainty, is not expected for $Q$-values which result in a mean initial $\beta$-energy over $\sim$2000 keV, i.e. $Q \geq 5$ MeV. Since all of the $Q$-values for the decays under consideration in this study are over this threshold (and in all cases the $Q$-value uncertainty is 500 keV or less), we do not expect the choice of $Q$-value for our simulations to impact the results for the $\beta$-energy deposition and therefore for $\beta$-summing. This insensitivity to the $Q$-value ultimately allows a higher-statistics $\beta$-delayed proton emission decay branches to be used to determine the $\beta$-summing correction for a lower-statistics decay branch with a roughly similar $Q$-value, as was done for $^{69}$Kr in Reference [1].

3. Novel implantation depth determination method

The amount of $\beta$-summing which occurs for a given $\beta$p emission depends sensitively on the depth within the DSSD at which the $\beta$p emission occurs. A deeper depth within the DSSD implies that the emitted $\beta$ travels through more material while escaping the implantation DSSD and thus deposits more energy, on average, when compared to a $\beta$p emission at a shallower depth. Though the stochastic nature of implantation depth and $\beta$ energy-loss reduces the strength of the previous statement, it remains true for an ensemble of $\beta$p emissions. Thus, the determination of the mean implantation depth of a $\beta$p emitter substantially reduces the uncertainty associated with implementing the $\beta$-summing correction for proton-energy determination. Typically, the two available methods for determining implantation depth, described in the following section (Section 4), are dependent on the energy calibration of three DSSDs and similar response to $\beta$-particles of the
same energy for two DSSDs. Instead, our method, which is outlined in this section, relies on the energy calibration of only a single DSSD. Note that the independence from detector threshold is true for the majority of $\beta$-delayed proton emission experiments since proton energies are usually $\gtrsim 1$ MeV, while the detection threshold plays no role above $\sim 0.5$ MeV, as seen in Figure 3. Consequently, our method provides an efficient way to minimize systematic uncertainties present for the $\beta$-summing correction.

In simulating $\beta$-delayed proton emission we include the energy and angle of the decay products and the position of the $\beta p$-emitter within the DSSD, each of which is sampled from a probability distribution event-by-event. We sample the positron energy from the well-understood $\beta$-decay distribution given by the Fermi theory of $\beta$-decay [15], including corrections to $\beta$-energy deposition that mimic detector resolution and detector threshold. Corrections for detector threshold and resolution are applied to the discrete proton energy and deposited $\beta$ energy. The distributions for proton and positron emission angles are isotropic, since the orientations of nuclei stopped within the DSSD are random. The $\beta$-decay position on the plane of the DSSD that is perpendicular to the beam-direction is selected from a two-dimensional skew Gaussian which was fitted to the measured implantation distribution, which was possible due to the segmentation of the DSSD into virtual pixels. As the implantation depth for a given $\beta$-delayed proton emission event is $a \text{ priori}$ unknown due to the lack of segmentation in the depth-dimension of the DSSD, the depth of the $\beta p$-emitter within the implantation DSSD is selected from a skew Gaussian distribution that is fitted to the implantation depth distribution simulated with the multi-purpose simulation tool LISE++ [25] (using their Straggling Method 1) for the $\beta$-delayed proton emission experiments discussed here. We stress that LISE++ is not able to accurately predict the absolute implantation depth of $\beta p$ nuclei within the implantation DSSD, hence the need for the adjustable aluminum degrader upstream of the BCS (See Figure 1.), though we find it accurately predicts the relative separation in mean implantation depth for ions measured in the same projectile fragmentation experiment (See Section 4.). The implantation depth distributions for the simulated $\beta p$ nuclei, shown in Figure 7, in general span roughly 1/3 of the 0.525 mm DSSD thickness. The widths of the distributions are due to the narrow momentum acceptance, $\pm 0.67\%$ and $\pm 0.5\%$ for the $^{78}$Kr and $^{40}$Ar primary beams, respectively, of the fragment separator. The centroid of an implantation depth distribution is referred to here as the mean implantation depth. Figure 8 shows the impact of choosing different discrete depths within the DSSD to simulate the $\beta$-delayed proton-emission event on energy deposition of $\beta$-particles emitted within the implantation DSSD.

The centroid of the depth distribution function from which the $\beta p$-implantation depth was sampled was changed in 5 $\mu$m steps from 0 to 260 $\mu$m between simulations, where these depths correspond to the upstream-face and center-plane of the DSSD, respectively. Due to the symmetry of the detector, equivalent results are obtained by choosing centroids from 525 to 265 $\mu$m. However, this degeneracy is not an issue, as an accurate $\beta$-summing correction only relies on knowing the distance between the centroid and closest DSSD planar surface. As will be shown in the following section, we find our mean implantation depth determination method has a precision on the order of tens of microns, and thus we find a 5 $\mu$m grid to be sufficient.

![Figure 7: (color online.) Probability distributions for the implantation depths of $^{67}$Se, $^{20}$Mg, $^{23}$Si, and $^{69}$Kr ions within a 0.525 mm-thick DSSD calculated with LISE++ [25] using their Straggling Method 1. The amplitudes and centroids of each distribution have been shifted arbitrarily for comparison. The distribution shape is primarily related to the ion’s momentum distribution, which depends on the ion production mechanism, e.g. target thickness and momentum-acceptance of the fragment separator through which the ions pass.](image7)

![Figure 8: (color online.) $\beta$-particle energy-deposition histograms from GEANT4 simulations of $^{67}$Se $\beta^+$-emission at various depths within a 525 $\mu$m DSSD, where a detection threshold has not been applied. In each case the angular distribution of the $\beta^+$-emission was isotropic.](image8)
in the following section. The precise mean implantation depth is important because it corresponds to a reduction in the proton-decay energy uncertainty that results from the β-summation correction, as discussed in Section 5. This method provides a way to determine mean implantation depth of a βp emitter which can be used in addition to or in lieu of (if they are not feasible) the other methods of mean implantation depth determination discussed in the following section.

4. Other mean implantation depth determination methods

In order to validate our mean implantation depth determination method, ‘Method 1’, we compare it to other available methods. In addition to the method described in the prior section, we use two independent methods to determine the mean implantation depth for the β-delayed proton emitters 20Mg and 23Si.

4.1. Method 2: Implantations per implantation DSSD and upstream or downstream DSSDs

For the first additional method we look at the fraction of implantations of a given nucleus that occurs in the DSSDs which are neighbors to the implantation DSSD. This method requires that a nucleus is poorly centered...
4.2. Method 3: Mean \( \beta \) implantation depth distribution shape.

The method is reliant on an accurate prediction of the implantation depth distribution. Positrons which traveled through more silicon in the implantation DSSD on average lost more energy. Therefore, the positrons which traveled through more silicon in the implantation DSSD (and thus lost more energy in the implantation DSSD) implanted more energy in the neighboring DSSD when compared to positrons that traveled through less silicon in the implantation DSSD. This phenomenon, which is expected from the Bethe formula, was used by Reference [6] to gate on events that had minimal \( \beta \)-summing in their implantation DSSD.

Simulations were employed to map between mean implantation depth and the mean \( \beta \)-energy deposition difference between \( \beta \)-energy distributions for the upstream and downstream DSSDs. The results of this process for \( ^{23}\text{Si} \) are shown in Figure 12, where the reported mean implantation depth uncertainty is the simulated depth range that resulted in an upstream-downstream mean \( \beta \)-energy difference within the range given by the fitted mean-energy uncertainties summed in quadrature. We note that this method of mean implantation depth determination relies upon the DSSDs which are upstream and downstream of the implantation DSSD having a similar response to \( \beta \)-particles of the same energy.

4.3. Comparison between mean implantation depth determination methods

We find agreement between each of the three mean implantation depth determination methods for \( ^{20}\text{Mg} \) and \( ^{23}\text{Si} \), as seen in Table 2. The relative separation in mean implantation depth between \( ^{20}\text{Mg} \) and \( ^{23}\text{Si} \) is in good agreement with the separation predicted by LISE++, 180 \( \mu \text{m} \). Here we stress that the advantage of the method presented in Section 3 (Method 1 of Table 2), is that it only requires a single DSSD, namely the implantation DSSD, and therefore is only sensitive to the energy calibration and electronic noise of one rather than three DSSDs and it is generally not sensitive to the detector threshold of any DSSD. Additionally, we note that Methods 1 and 3 are more precise for \( \beta \) nuclei deposited closer to the center of the implantation DSSD, while Method 2 excels for \( \beta \) nuclei deposited nearer to the implantation DSSD surface.
5. Determination of the $\beta$-summing correction

The accurate mean implantation depth determination methods described in the previous sections (Sections 3 and 4) enable an accurate determination of the $\beta$-energy deposited in a $\beta$-delayed proton emission event within a DSSD, and thus allow for an accurate proton-decay energy to be determined. The methods’ typical precision of tens of microns results in an uncertainty in the $\beta$-summing correction which is on the order of tens of keV for the cases presented here.

The relationship between $\beta$-summing and mean implantation depth within a 525 $\mu$m DSSD for $^{23}$Si is shown in Figure 13. Under our conditions, an implantation depth distribution with $\sim$150 $\mu$m FWHM in a 525 $\mu$m-thick DSSD, we are able to determine the mean implantation depth within $\sim$40 $\mu$m; however, more accurate results would be possible for a narrower depth distribution in a thinner detector. As seen in Figure 13, the mean implantation depth uncertainty of 40 $\mu$m translates into a $\beta$-summing correction uncertainty of anywhere from 5 to 25 keV, depending on which place along the depth-correction relationship the mean implantation depth is located. Similarly for $^{20}$Mg, whose correction-range was found to be between 10 and 85 keV, the $\beta$-summing correction uncertainty for the range of possible mean implantation depths was between 5 and 15 keV. Given the determined implantation depth, the actual correction for the deduced mean implantation depth was 18±6 keV.

To correct for $\beta$-summing and determine the proton-decay energy from a $\beta$-delayed proton emitting nucleus, we incrementally iterate over proton-decay energies in the Monte Carlo simulation for each mean implantation depth. $\chi^2$ minimization between the energy-deposition histograms, which include the energy deposited by the proton+recoil and $\beta$-summing, from the data and simulations simultaneously results in a proton-decay energy and mean implantation depth. This procedure has been used for the $\beta$-delayed proton emission of $^{69}$Kr (using the 2.94 MeV proton-decay peak) to obtain a summing correction of 79±12 keV.[1]. Therefore, the full process of applying the $\beta$-summing correction to obtain a precise proton energy from a $\beta$-delayed proton emission measurement in a DSSD is the following:

1. Obtain the $\beta$p nucleus surface implantation distribution by fitting to the implantation distribution measured with the pixelated DSSD.
2. Obtain the $\beta$p implantation depth distribution by fitting to results from LiSE++ simulations that mimic experimental conditions, i.e. ion production, transport, and detector materials.
3. Perform Monte Carlo simulations for a given $\beta$-delayed proton decay branch with GEANT4, randomly selecting the $\beta$ energy and angle, proton angle, and $\beta$p decay location, for mean implantation depths ranging from the detector surface to detector center.
4. Perform $\chi^2$-minimization between the simulated and measured total (proton + recoil + $\beta$) energy-deposition histograms, allowing the location of the histogram peak to vary.
5. For the simulation which yields the minimum reduced-$\chi^2$, the location of the histogram peak simultaneously yields the proton-decay energy and the amount of $\beta$-summing (since the proton-decay energy deposited in the simulation can be plotted simultaneously with the total energy-deposition).
Figure 13: (color online.) Reduced-$\chi^2$ minimization from mean implantation depth determination Method 1 for $^{23}$Si as a function of mean implantation depth (left panel), where a quadratic fit is included to guide the eye, demonstrating a mean implantation depth of 250 $\pm$ 40 $\mu$m. The right panel shows the corresponding $\beta$-summing correction applied to $^{23}$Si proton energy deposition peaks as a function of mean implantation depth, where a third-order polynomial fit is included to guide the eye.

6. Conclusions

In summary, we present an approach to address the problem of $\beta$-summing in the measurement of proton-decay energies of $\beta$-delayed proton-emitting nuclei detected via implantation within a DSSD. We demonstrate that determination of the mean implantation depth of the $\beta$p nucleus within the implantation DSSD subsequently determines the magnitude of $\beta$-summing. We describe three methods to determine the mean implantation depth, two of which require DSSDs located upstream and downstream of the implantation DSSD and a third which depends only on the total (proton + recoil + $\beta$) energy-deposition histogram of the implantation DSSD and is generally insensitive to the detector threshold uncertainty. For the cases discussed, these techniques are capable of determining the mean implantation depth of a $\sim$ 100 MeV/u $\beta$p nucleus within a $\sim$0.5 mm-thick DSSD to within tens of microns, corresponding to a $\beta$-summing correction uncertainty of $<25$ keV.

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References